

Fast switching diode chip in EMCON-Technology

## FEATURES:

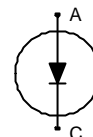
- 600V EMCON technology 70  $\mu\text{m}$  chip
- soft , fast switching
- low reverse recovery charge
- small temperature coefficient

## This chip is used for:

- EUPEC power modules and discrete devices

## Applications:

- SMPS, resonant applications, drives



Chip Type	$V_R$	$I_F$	Die Size	Package	Ordering Code
SIDC07D60F6	600V	22.5A	2.12 x 3.41 mm <sup>2</sup>	sawn on foil	Q67050-A4039-A001

## MECHANICAL PARAMETER:

Raster size	2.12 x 3.41	mm <sup>2</sup>
Area total / active	7.23 / 5.12	
Anode pad size	1.63 x 2.92	
Thickness	70	$\mu\text{m}$
Wafer size	150	mm
Flat position	180	deg
Max. possible chips per wafer	2000 pcs	
Passivation frontside	Photoimide	
Anode metallisation	3200 nm Al Si 1%	
Cathode metallisation	1400 nm Ni Ag –system suitable for epoxy and soft solder die bonding	
Die bond	electrically conductive glue or solder	
Wire bond	Al, $\leq 500\mu\text{m}$	
Reject Ink Dot Size	$\varnothing$ 0.65mm ; max 1.2mm	
Recommended Storage Environment	store in original container, in dry nitrogen, < 6 month at an ambient temperature of 23°C	

## Maximum Ratings

Parameter	Symbol	Condition	Value	Unit
Repetitive peak reverse voltage	$V_{RRM}$		600	V
Continuous forward current limited by $T_{jmax}$	$I_F$		22.5	A
Single pulse forward current (depending on wire bond configuration)	$I_{FSM}$	$t_P = 10\text{ ms sinusoidal}$	tbd	
Maximum repetitive forward current limited by $T_{jmax}$ (depending on wire bond configuration)	$I_{FRM}$		45	
Operating junction and storage temperature	$T_j, T_{stg}$		-55...+150	°C

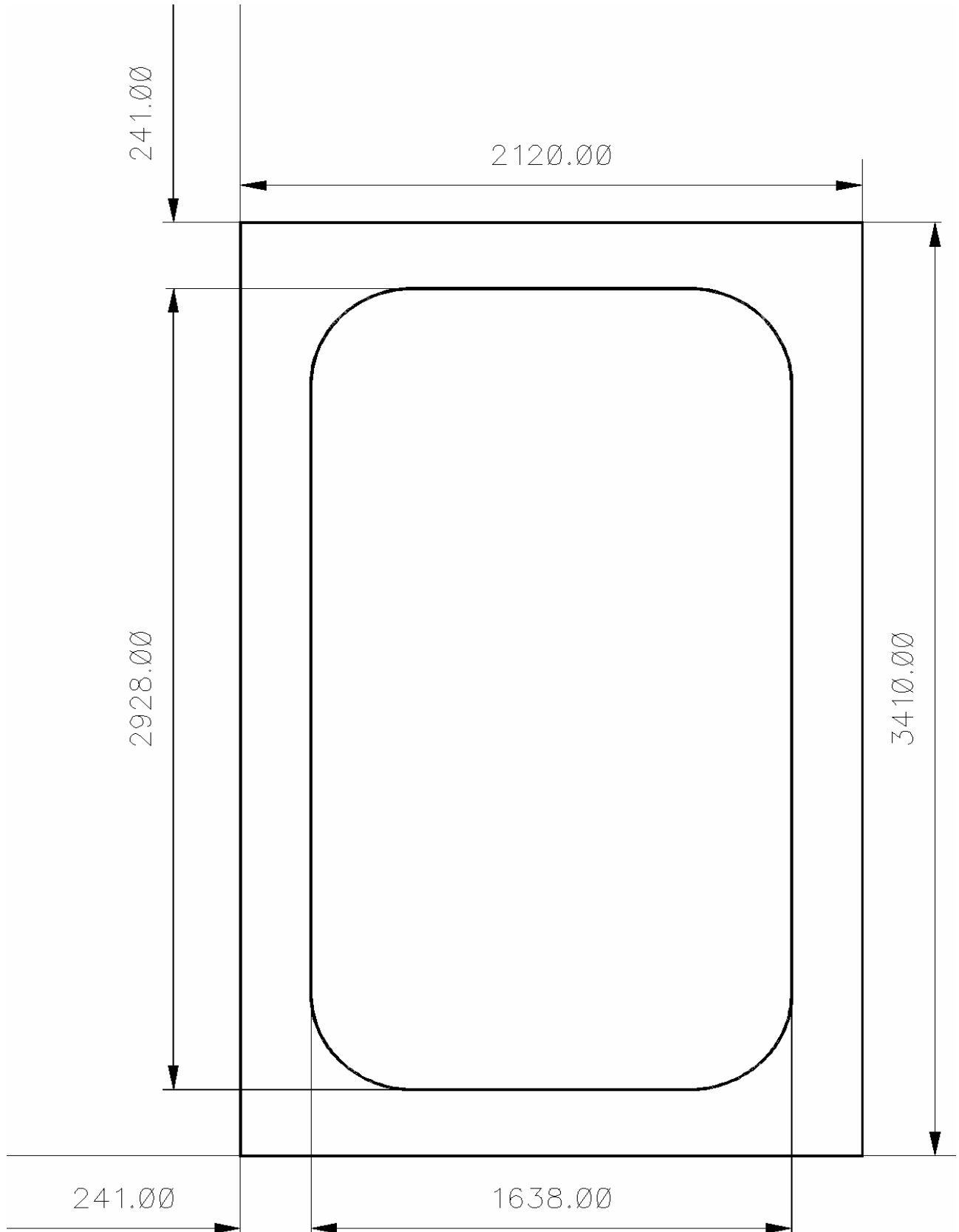
## Static Electrical Characteristics (tested on chip), $T_j=25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Conditions		Value			Unit
				min.	Typ.	max.	
Reverse leakage current	$I_R$	$V_R=600\text{ V}$	$T_j=25\text{ °C}$			250	µA
Cathode-Anode breakdown Voltage	$V_{Br}$	$I_R=1.5\text{ mA}$	$T_j=25\text{ °C}$	600			V
Forward voltage drop	$V_F$	$I_F=22.5\text{ A}$	$T_j=25\text{ °C}$		1.45		V

## Dynamic Electrical Characteristics, at $T_j = 25\text{ °C}$ , unless otherwise specified, tested at component

Parameter	Symbol	Conditions		Value			Unit
				min.	Typ.	max.	
Reverse recovery time	$t_{rr1}$	$I_F=22.5\text{ A}$	$T_j = 25\text{ °C}$		120		ns
	$t_{rr2}$	$di/dt=1000\text{ A/ms}$ $V_R=400\text{ V}$	$T_j = 150\text{ °C}$		170		
Peak recovery current	$I_{RRM1}$	$I_F=22.5\text{ A}$	$T_j = 25\text{ °C}$		17		A
	$I_{RRM2}$	$di/dt=1000\text{ A/ms}$ $V_R= 400\text{ V}$	$T_j = 150\text{ °C}$		21.5		
Reverse recovery charge	$Q_{rr1}$	$I_F=22.5\text{ A}$	$T_j=25\text{ °C}$		970		nC
	$Q_{rr2}$	$di/dt=1000\text{ A/ms}$ $V_R= 400\text{ V}$	$T_j=150\text{ °C}$		1770		
Peak rate of fall of reverse recovery current	$di_{rr1}/dt$	$I_F=22.5\text{ A}$	$T_j = 25\text{ °C}$				A/µs
	$di_{rr2}/dt$	$di/dt=1000\text{ A/ms}$ $V_R= 400\text{ V}$	$T_j=150\text{ °C}$				
Softness	S1	$I_F=22.5\text{ A}$	$T_j=25\text{ °C}$		4.4		1
	S2	$di/dt=1000\text{ A/ms}$ $V_R= 400\text{ V}$	$T_j=150\text{ °C}$		5		

CHIP DRAWING:



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**FURTHER ELECTRICAL CHARACTERISTICS:**

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This chip data sheet refers to the  
device data sheet

INFINEON TECHNOLOGIES /  
EUPEC

tbd

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**Description:**

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AQL 0,65 for visual inspection according to failure catalog

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Electrostatic Discharge Sensitive Device according to MIL-STD 883

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Test-Normen Villach/Prüffeld

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